```
S1:  (49)  365/147.ccls.
S2:  (23)  S1 and light
S3:  (26)  S1 and (light or optical)
S4:  (77565)  "365"/S.ccls.
S5:  (4279)  ((optical$3 or light or radiation or laser) and electrical$3) near4 (program$5 or eras$3)
S6:  (937)  S4 and S5
S7:  (150)  ((optical$3 or light or radiation or laser) and electrical$3) near4 (program$5 or eras$...
S8:  (20)  S7 and S4
S9:  (3690)  (365/163,148,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S10:  (723)  S9 and laser
S11:  (1050)  (365/163,148,215,113,34,234).ccls.
S12:  (323)  S11 and laser
S13:  (0)  "opticalled accessible phase".ti.
S14:  (2)  "20050030784"
S15:  (20154)  memory with laser
S19:  (796)  chalcogenide with light
S20:  (1946)  chalcogenide with (light or laser or optical$3)
S21:  (3690)  (365/163,148,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S22:  (104)  S20 and S21
S23:  (1062)  chalcogenide with (light or laser or optical$3) and (read$3 or sens$3 or access$3)
S24:  (93)  S23 and S21
S25:  (207)  chalcogenide with ((light or laser or optical$3) and (read$3 or sens$3 or access$3))
S26:  (34)  S25 and S21
S27:  (3396)  (365/163,215,113,34,234 or 438/95 or 257/52,53,16,60).ccls.
S28:  (570200)  ((light or laser or optical$3) near6 (read$3 or sens$3 or access$3))
S29:  (580)  S28 and S27
S30:  (389)  (365/163,113,34).ccls.
S31:  (86)  S30 and S28
S32:  (18)  Combined citation search 1
S33:  (7747)  micro$1mirror
S34:  (2)  S27 and S33
S35:  (9)  US-5543737-S.DID. OR US-5694146-S.DID. OR US-5757446-S.DID. OR US-5166758-S.DID. OR US-5...
S36:  (530)  ovshinsky.in.
S37:  (168)  S36 and optical
S38:  (28)  S36 and (optical$3 with read$3)
S39:  (0)  S36 and (optical$3 near5 read$3) same electrical$4 near5 (program$4 or writ$3)
S40:  (2)  opto$1electric near4 (memory or cell) and S27
S41:  (1)  "6967344".pn.
S42:  (3)  "10426321"
S43:  (352)  (optical$3 near5 read$3) same electrical$4 near5 (program$4 or writ$3)
S44:  (11)  S43 and S21
S45:  (43)  read$3 with chalcogenide with (optical$3 or laser)
S46:  (150)  JOHNSON-bRIAN.in.
S47:  (124)  JOHNSON-bRIAN.in. and memory
S48:  (0)  JOHNSON-bRIAN.in. and "phase change"
S49:  (7)  JOHNSON-bRIANS.in. and "phase change"
S50:  (11)  ("20040178403"|"20040245603"|"4203123"|"5166758"|"5914893"|"5933365"|"6189582"|"6225142...
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1	☑	☐	US 20040245603 A1	20041209	37	Electrically programmable memory element with improved	257/536	257/E27.004; 257/E45.002	Lowrey, Tyler et al.	☐	☐	☐	☐	☐	☐	☐	US 20040245603		

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